DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

Application Number

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

	MOS STACKED-GATE MEM CONTROL GATE VOLTAGE	ORY CELL PROGRAMMING ENHANCEMEN	NT UTILIZING STAIR-
the specification o No. 10/664,469 ar Declaration.	f which (check one)	ached hereto or was filed on <u>September 1.</u> ary Amendment filed in the U.S. Patent Office	7, 2003 as Application on the same date as this
I hereby state that claims, as amende	I have reviewed and understed by any amendment referre	and the contents of the above-identified spec d to above.	ification, including the
I acknowledge the	duty to disclose all information	on which is material to patentability as defined	d in 37 CFR § 1.56.
or inventor's certifithan the United St	cate, or § 365(a) of any PCT ates, listed below and have a	U.S.C. § 119(a)-(d) or § 365(b) of any foreign International application which designated at also identified below any foreign application for application on which priority is claimed:	least one country other
Prior Foreign Appl	ication(s)		Priority Claimed Yes No
Number	Country	Day/Month/Year Filed	
Number	Country	Day/Month/Year Filed	
I hereby claim the	benefit under 35 U.S.C. § 11	9(3) of any United States provisional applicat	ion(s) below:
Application Number	er	Filing Date	
Application Number	er	Filing Date	

Filing Date

I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose all information which is material to patentability as defined in 37 CFR § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

Application Number	Filing Date	Status: Patented, Pending, Abandoned
Application Number	Filing Date	Status: Patented, Pending, Abandoned
Application Number	Filing Date	Status: Patented, Pending, Abandoned

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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